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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
10/563,120	01/03/2006	Kohichi Morino	R2184.0472/P472	8029
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DICKSTEIN SHAPIRO LLP 1825 EYE STREET NW Washington, DC 20006-5403			EXAMINER O TOOLE, COLLEEN J	
			ART UNIT 2816	PAPER NUMBER
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Please find below and/or attached an Office communication concerning this application or proceeding.

The time period for reply, if any, is set in the attached communication.

## Office Action Summary

Application No.

10/563,120

Applicant(s)

MORINO ET AL.

Examiner

Colleen O'Toole

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-- The MAILING DATE of this communication appears on the cover sheet with the correspondence address --

### Period for Reply

A SHORTENED STATUTORY PERIOD FOR REPLY IS SET TO EXPIRE 3 MONTH(S) OR THIRTY (30) DAYS, WHICHEVER IS LONGER, FROM THE MAILING DATE OF THIS COMMUNICATION.

- Extensions of time may be available under the provisions of 37 CFR 1.136(a). In no event, however, may a reply be timely filed after SIX (6) MONTHS from the mailing date of this communication.
- If NO period for reply is specified above, the maximum statutory period will apply and will expire SIX (6) MONTHS from the mailing date of this communication.
- Failure to reply within the set or extended period for reply will, by statute, cause the application to become ABANDONED (35 U.S.C. § 133). Any reply received by the Office later than three months after the mailing date of this communication, even if timely filed, may reduce any earned patent term adjustment. See 37 CFR 1.704(b).

### Status

- 1) ☒ Responsive to communication(s) filed on 03 January 2006.
- 2a) ☐ This action is FINAL. 2b) ☒ This action is non-final.
- 3) ☐ Since this application is in condition for allowance except for formal matters, prosecution as to the merits is closed in accordance with the practice under *Ex parte Quayle*, 1935 C.D. 11, 453 O.G. 213.

### Disposition of Claims

- 4) ☒ Claim(s) 1-11 is/are pending in the application.
- 4a) Of the above claim(s) \_\_\_\_\_ is/are withdrawn from consideration.
- 5) ☐ Claim(s) \_\_\_\_\_ is/are allowed.
- 6) ☒ Claim(s) 1-11 is/are rejected.
- 7) ☐ Claim(s) \_\_\_\_\_ is/are objected to.
- 8) ☐ Claim(s) \_\_\_\_\_ are subject to restriction and/or election requirement.

### Application Papers

- 9) ☒ The specification is objected to by the Examiner.
- 10) ☐ The drawing(s) filed on \_\_\_\_\_ is/are: a) ☐ accepted or b) ☐ objected to by the Examiner.
- Applicant may not request that any objection to the drawing(s) be held in abeyance. See 37 CFR 1.85(a).  
Replacement drawing sheet(s) including the correction is required if the drawing(s) is objected to. See 37 CFR 1.121(d).
- 11) ☐ The oath or declaration is objected to by the Examiner. Note the attached Office Action or form PTO-152.

### Priority under 35 U.S.C. § 119

- 12) ☒ Acknowledgment is made of a claim for foreign priority under 35 U.S.C. § 119(a)-(d) or (f).
- a) ☒ All b) ☐ Some \* c) ☐ None of:
- 1) ☒ Certified copies of the priority documents have been received.
  - 2) ☐ Certified copies of the priority documents have been received in Application No. \_\_\_\_\_.
  - 3) ☐ Copies of the certified copies of the priority documents have been received in this National Stage application from the International Bureau (PCT Rule 17.2(a)).
- \* See the attached detailed Office action for a list of the certified copies not received.

### Attachment(s)

- 1) ☒ Notice of References Cited (PTO-892)
- 2) ☐ Notice of Draftsperson's Patent Drawing Review (PTO-948)
- 3) ☒ Information Disclosure Statement(s) (PTO/SB/08)  
Paper No(s)/Mail Date 1/3/06
- 4) ☐ Interview Summary (PTO-413)  
Paper No(s)/Mail Date. \_\_\_\_\_
- 5) ☐ Notice of Informal Patent Application
- 6) ☐ Other: \_\_\_\_\_

## DETAILED ACTION

### *Specification*

1. The disclosure is objected to because of the following informalities: On page 12, line 22, the number "12" should be replaced by --11-- to agree with Figure 2.

Appropriate correction is required.

### *Claim Rejections - 35 USC § 102*

1. The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless –

(b) the invention was patented or described in a printed publication in this or a foreign country or in public use or on sale in this country, more than one year prior to the date of application for patent in the United States.

2. Claims 1-4 and 6 are rejected under 35 U.S.C. 102(b) as being anticipated by Matsuda et al. (U.S. Patent 5,861,771 as recited in the Information Disclosure Statement dated January 3, 2006, hereafter Matsuda).

Claim 1: Matsuda teaches a semiconductor device (Figure 4) comprising:

a high-breakdown-voltage regulator (7) configured to operate at a high input voltage ( $V_{cc1}$ );

a reference voltage generating circuit (41) structured as a low-breakdown-voltage component (voltage divider VR) and configured to receive an output voltage (VR) from the high-breakdown-voltage regulator (7) to generate a reference voltage ( $V_{ref}$ );

a differential amplifier circuit (51) structured as another low-breakdown-voltage component (voltage divider VR) and configured to receive the output voltage (VR) from

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the high-breakdown-voltage regulator (7) and the reference voltage ( $V_{ref}$ ) from the reference voltage generating circuit (41) to produce a drive voltage ( $V_c$ );

an output driver (63) structured as a high-breakdown-voltage component (via  $V_{cc1}$ ) and configured to operate based on the drive voltage ( $V_c$ ); and

resistors ( $R_3$  and  $R_4$ ) connected in series to the output driver (63) to divide an output voltage ( $V_{cc2}$ ) of the output driver (63) and feed the divided voltage ( $V_f$ ) back to the differential amplifier circuit (51).

Claim 2: Matsuda further teaches that the high-breakdown-voltage output driver (6) and the low-breakdown-voltage components (4 and 5) are MOS transistors with gate oxide films having a first thickness (column 2 lines 41-44).

Claim 3: Matsuda further teaches that the high-breakdown-voltage regulator is structured by a high-breakdown-voltage MOS transistor with a gate oxide film having a second thickness greater than the first thickness (inherent because the size of 4, 5, and 6 are reduced; column 2 lines 41-44).

Claim 4: Matsuda teaches that the output driver (63; Figure 4) is a P-channel MOS transistor (from Figure 4). Matsuda also teaches a diode (62 is a diode-connected transistor) inserted between the gate and the source of the P-channel MOS transistor (63) and having a breakdown voltage lower than an oxide breakdown voltage of the P-channel MOS transistor.

Claim 6: Matsuda further teaches that the output driver (63; Figure 4) is a P-channel MOS transistor (as seen in Figure 4), the semiconductor device further comprising a constant current inverter inserted between the differential amplifier circuit and the output driver, the constant current inverter comprising:

- a constant current circuit (62) connected between a power supply line (Vcc1) and the output driver (63); and

- a MOS transistor (61) controlled by the drive voltage output (Vc) from the differential amplifier circuit (51).

### ***Claim Rejections - 35 USC § 103***

3. The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:

(a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negated by the manner in which the invention was made.

4. Claims 5 and 7 are rejected under 35 U.S.C. 103(a) as being unpatentable over Matsuda.

Claim 5: Claim 5 recites the same limitations as claim 4, but using an N-channel MOS transistor. It would have been obvious to one of ordinary skill in the art at the time the invention was made to have used an N-channel MOS transistor instead of a P-channel MOS transistor and therefore claim 5 is rejected for the same reasons as claim 4 above. The selection of something based on its known suitability for its intended use has been

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held to support a *prima facie* case of obviousness. *Sinclair & Carroll Co. v.*

*Interchemical Corp.*, 325 U.S. 327, 65 USPQ 297 (1945).

Claim 7: Matsuda further teaches that the output driver is a P-channel MOS transistor (63; Figure 4), the semiconductor device further comprising a constant current inverter (6) inserted between a power supply line (Vcc1) and the output driver (63), the constant current inverter (6) comprising:

- a first N-channel MOS transistor (61) to which the reference voltage (Vref) generated by the reference voltage generator is supplied (via 51);

- a first P-channel MOS transistor (62) connected in series to the first N-channel MOS transistor (61) to produce a constant current (mirrors current from 61);

- a second P-channel MOS transistor (63) defining a constant current circuit under a current mirror configuration (mirrors current from 62); and

Matsuda does not explicitly teach a second N-channel MOS transistor to which the drive voltage output from the differential amplifier circuit is supplied. However, it is known in the art to use self-biased MOS transistors to be resistive components R3 and R4.

Therefore, it would have been obvious to one of ordinary skill in the art at the time the invention was made to have used a second N-channel MOS transistor to drive the voltage output from the differential amplifier for resistor R3. The selection of something based on its known suitability for its intended use has been held to support a *prima facie* case of obviousness. *Sinclair & Carroll Co. v. Interchemical Corp.*, 325 U.S. 327, 65 USPQ 297 (1945).

Claims 8 and 11 are rejected under 35 U.S.C. 103(a) as being unpatentable over Matsuda in view of Iravani (U.S. Patent 5,936,460). Matsuda teaches a semiconductor device (Figure 4) comprising:

- a reference voltage generating circuit (41) configured to generate a reference voltage ( $V_{ref}$ );

- a differential amplifier circuit (51) configured to receive the reference voltage ( $V_{ref}$ ) and generates a drive voltage ( $V_c$ );

- an output driver (63) configured to operate based on the drive voltage ( $V_c$ );

- resistors ( $R_3$  and  $R_4$ ) connected in series to the output driver (63) to divide an output voltage ( $V_{cc2}$ ) of the output driver (63) and feed the divided voltage ( $V_f$ ) back to the differential amplifier circuit (51). Matsuda does not teach a constant current circuit. Iravani teaches a constant current circuit (Figure 2) inserted between a power supply line ( $V_{dd}$ ) and a combination of the reference voltage generating circuit ( $I_{ref1}$  connected to  $V_{ref}$  of Matsuda) and the differential amplifier circuit ( $I_{ref2}$  connected to 61 of Matsuda). It would have been obvious to one of ordinary skill in the art at the time the invention was made to have used the current source taught by Iravani in the regulator circuit taught by Matsuda to provide a stable, noise-free output current (column 3 lines 58-59).

Claim 11: Iravani further teaches that the constant current circuit (Figure 2) is structured by multiple MOS transistors connected in series to form a multi-stage constant current circuit (61 of Matsuda is in series with m1 of Iravani).

5. Claims 9 and 10 are rejected under 35 U.S.C. 103(a) as being unpatentable over Matsuda and Iravani as applied to claim 8 above, and further in view of Menegoli et al. (U.S. Patent Application Publication 2004/0046532, hereafter Menegoli). Matsuda teaches the circuit as recited in claim 8 above. Matsuda does not teach that the constant current circuit (7; Figure 6) is structured by depression-mode or enhancement mode NMOS or PMOS transistor. Menegoli teaches that MOSFET transistors can be made either enhancement or depletion by adjusting the surface concentration of the channel region. Therefore, it would have been obvious to one of ordinary skill in the art at the time the invention was made to have used enhancement or depletion mode NMOS or PMOS transistors to adjust the threshold of the NMOS or PMOS transistors ([0020]).

### ***Conclusion***

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Colleen O'Toole whose telephone number is (571) 270-1273. The examiner can normally be reached on M-F 8:30-5:00pm EST.



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If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Drew Richards can be reached on (571) 272-1736. The fax phone number for the organization where this application or proceeding is assigned is 571-273-8300.

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see <http://pair-direct.uspto.gov>. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free). If you would like assistance from a USPTO Customer Service Representative or access to the automated information system, call 800-786-9199 (IN USA OR CANADA) or 571-272-1000.

  
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PRIMARY EXAMINER  
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